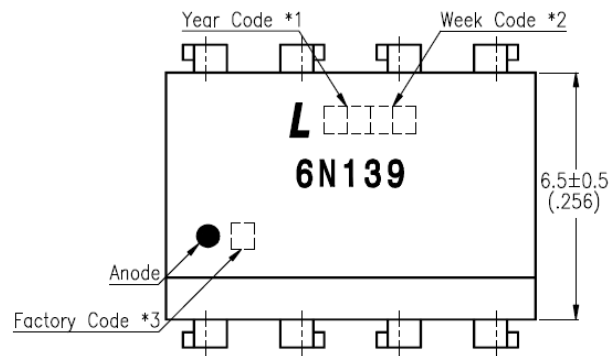
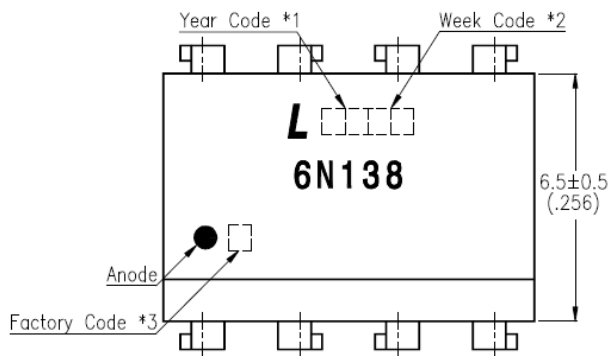


Ordering Information

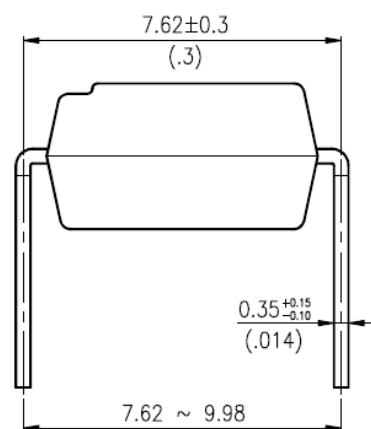
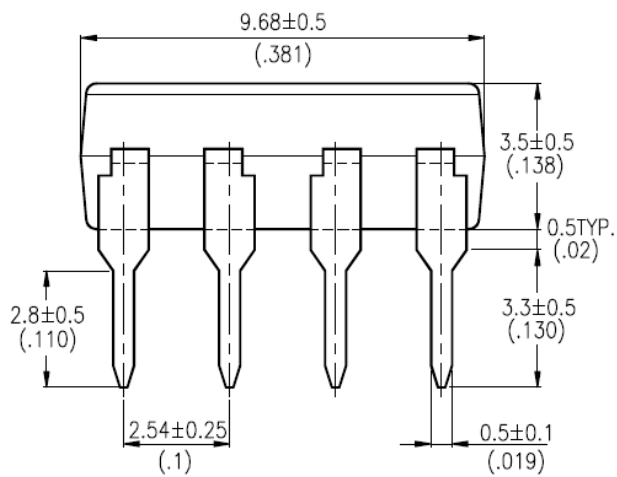
Part	Option	Minimum CMR		CTR	Remarks
		dV/dt (V/μs)	V _{CM} (V)		
6N138	M	1,000	10	400	Single Channel, DIP-8
	S				Single Channel, Wide Lead Spacing
6N139	M	1,000	10	300	Single Channel, SMD-8
	S				Single Channel, DIP-8
	M	1,000	10	300	Single Channel, Wide Lead Spacing
	S				Single Channel, SMD-8

OUTLINE DIMENSIONS

8-pin DIP Package (6N138 / 6N139)

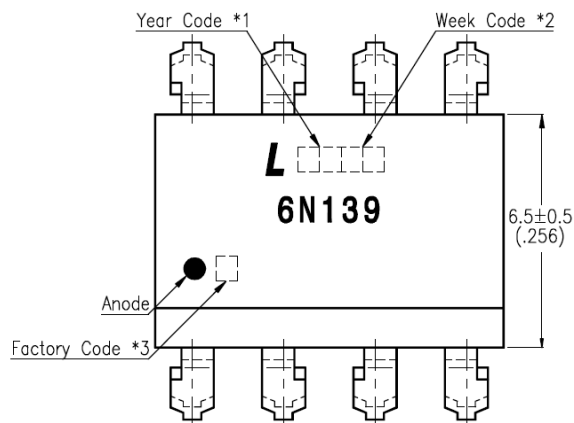
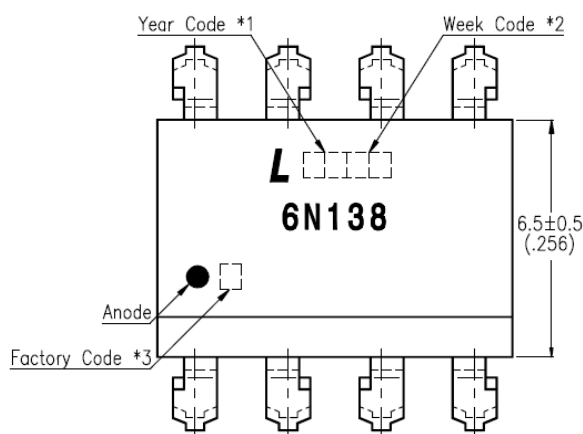


- *1. Year date code.
 - *2. 2-digit work week.
 - *3. Factory identification mark
(Z : Taiwan, Y : Thailand).
- Dimensions are in Millimeters and (Inches).



OUTLINE DIMENSIONS

8-pin DIP Wide Lead Spacing Package (6N138M / 6N139M)

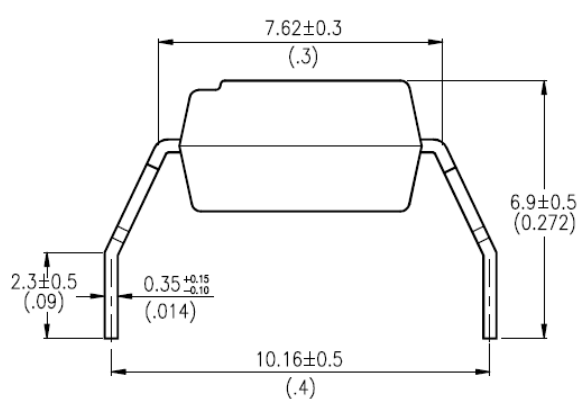
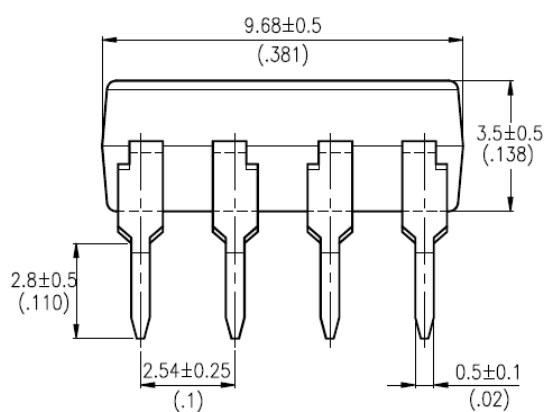


*1. Year date code.

*2. 2-digit work week.

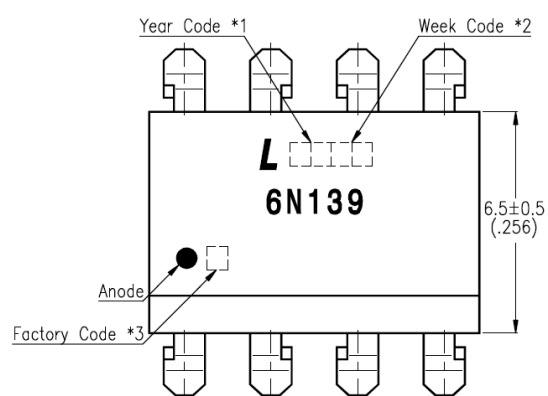
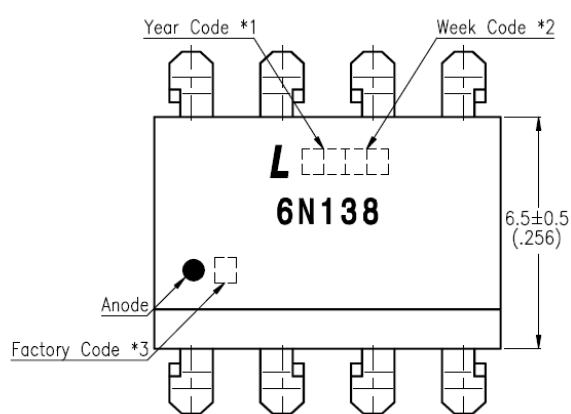
*3. Factory identification mark
(Z : Taiwan, Y : Thailand).

Dimensions are in Millimeters and (Inches).

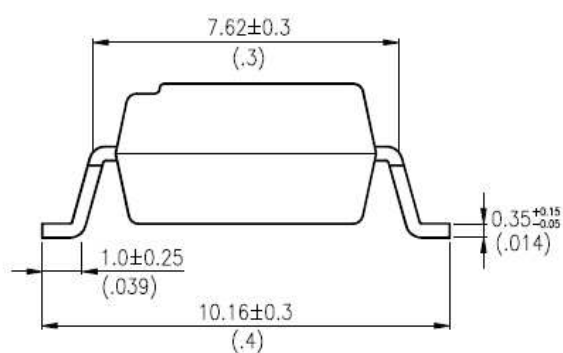
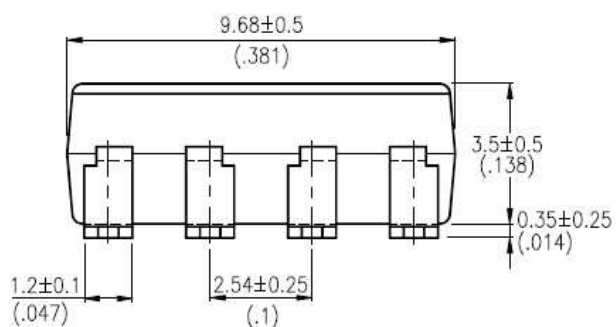


OUTLINE DIMENSIONS

8-pin DIP Surface Mount Package (6N138S / 6N139S)

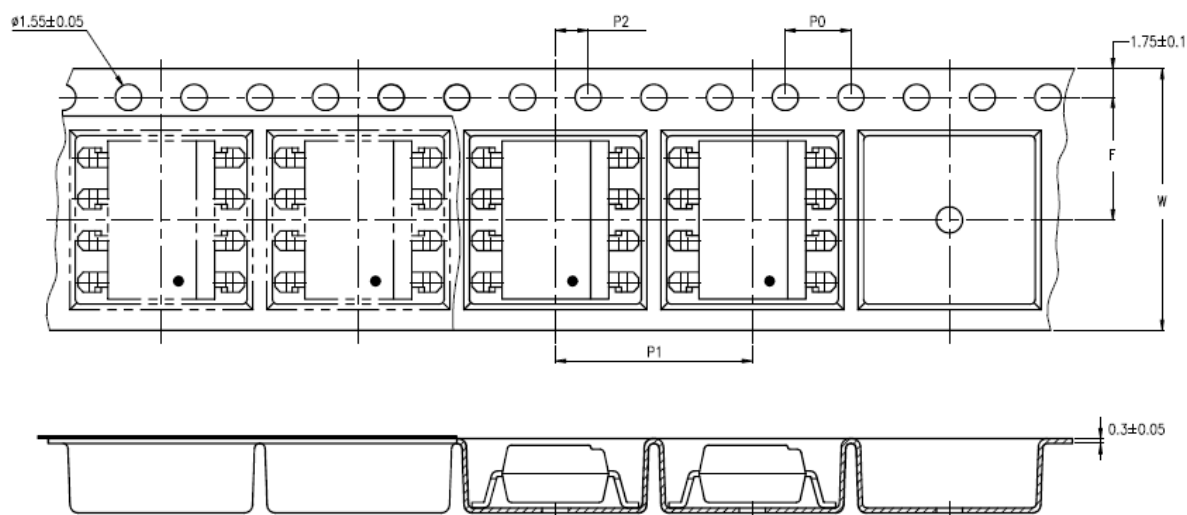


- *1. Year date code.
 - *2. 2-digit work week.
 - *3. Factory identification mark
(Z : Taiwan, Y : Thailand).
- Dimensions are in Millimeters and (Inches).

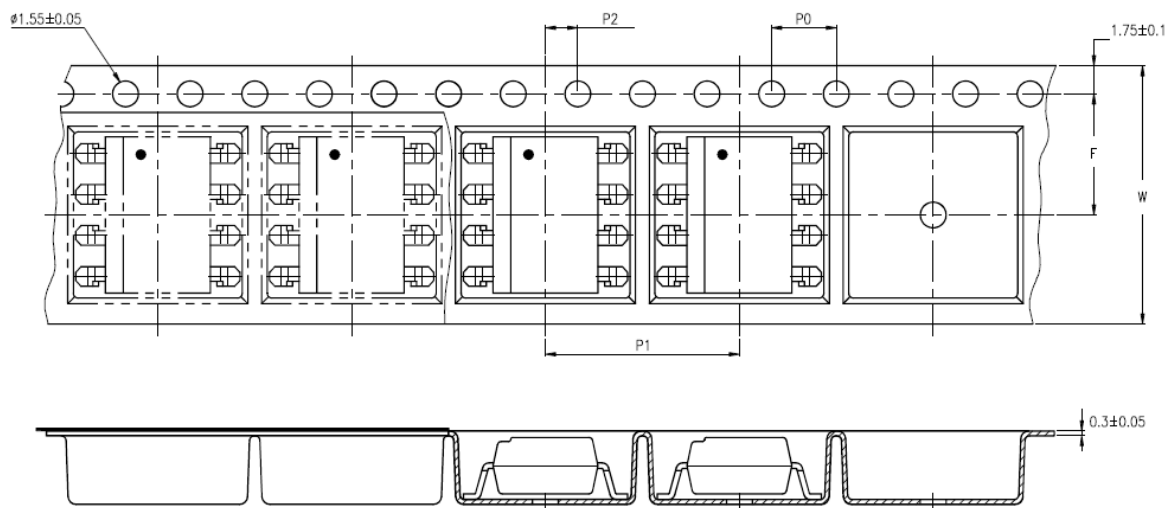


TAPING DIMENSIONS

6N138S/6N139S-TA



6N138S/6N139S-TA1

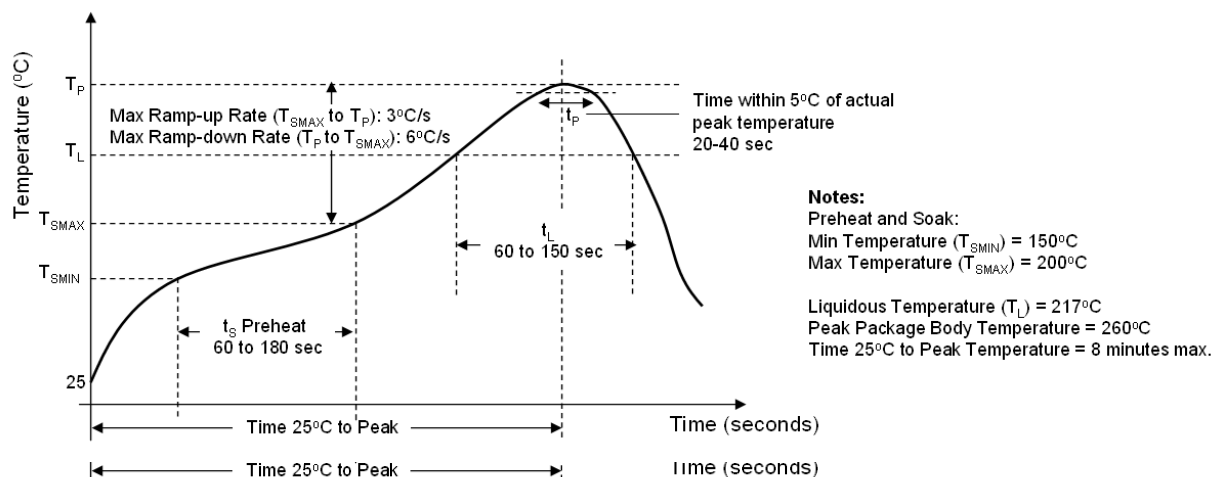


Description	Symbol	Dimensions in millimeters (inches)
Tape wide	W	16 ± 0.3 (.63)
Pitch of sprocket holes	P0	4 ± 0.1 (.15)
Distance of compartment	F P2	7.5 ± 0.1 (.295) 2 ± 0.1 (.079)
Distance of compartment to compartment	P1	12 ± 0.1 (.472)

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Recommended Lead Free Reflow Profile



Absolute Maximum Ratings*1

Parameter	Symbol	Device	Min	TYP	Max	Units
Storage Temperature	T _{ST}	6N138 6N139	-55		125	°C
Operating Temperature	T _A		-20		85	°C
Isolation Voltage	V _{ISO}		5000			V _{RMS}
Supply Voltage	V _{CC}				15	V
Lead Solder Temperature * 2	T _{SOL}				260	°C
Input						
Average Forward Input Current	I _F	6N138 6N139			20	mA
Reverse Input Voltage	V _R				5	V
Input Power Dissipation	P _I				35	mW
Output						
Average Output Current	I _O	6N138 6N139			50	mA
Supply Voltage, Output Voltage	V _{CC} , V _O	6N138	-0.5		7	V
		6N139	-0.5		18	
Output Collector Power Dissipation	P _O	6N138 6N139			100	mW

1. Ambient temperature = 25°C, unless otherwise specified. Stresses exceeding the absolute maximum ratings can cause permanent damage to the device. Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

2. 260°C for 10 seconds. Refer to Lead Free Reflow Profile.

Electrical Specifications

Parameters	Test Condition	Symbol	Device	Min	Typ	Max	Units
Input							
Input Forward Voltage	I _F =1.6mA, T _A =25°C	V _F	6N138 6N139		1.1	1.7	V
Input Forward Voltage Temperature Coefficient	IF=1.6mA	ΔV _F /ΔTa			-1.9		mV/°C
Input Reverse Voltage	I _R = 10μA T _A =25°C	BV _R		5	-	-	V
Input Capacitance	V _F =0; f=1MH _Z	C _{IN}		-	60	-	pF
Detector							
Current transfer ratio	I _F =1.6mA;Vo=0.4V; Vcc=4.5V	CTR	6N138	300	1600	2600	%
	I _F =0.5mA;Vo=0.4V; Vcc=4.5V		6N139	400	2000	5000	
	I _F =1.6mA;Vcc=0.4V; Vcc=4.5V			500	1600	2600	
Logic low output voltage	I _F =1.6mA;Vcc=4.5V; I _o =4.8mA	V _{OL}	6N138	-	0.1	0.4	V
	I _F =0.5mA;Vcc=4.5V; I _o =2mA		6N139	-	0.1	0.4	
	I _F =1.6mA;Vcc=4.5V; I _o =8mA			-	0.1	0.4	
	I _F =5mA;Vcc=4.5V; I _o =15mA			-	0.2	0.4	
	I _F =12mA;Vcc=4.5V; I _o =24mA			-	0.2	0.4	
Logic high output current	I _F =0mA, Vo=Vcc=7V T _A =25°C	I _{OH}	6N138	-	0.05	250	μA
	I _F =0mA, Vo=Vcc=18V T _A =25°C		6N139	-	0.1	100	
Logic low supply current	I _F =1.6mA, V _o =open (Vcc=18V)	I _{ccL}	6N138 6N139	-	0.4	1.5	mA
Logic high supply current	I _F =0mA, V _o =open ; T _A =25°C (Vcc=18V)	I _{ccH}	6N138 6N139	-	0.01	10	uA

*All Typical at $T_A = 25^\circ\text{C}$

SWITCHING SPECIFICATIONS (AC)

$T_A=0\sim70^{\circ}\text{C}$, $V_{CC}=5\text{V}$, unless otherwise specified.

Parameter	Test Condition	Symbol	Device	Min	Typ	Max	Units
Propagation Delay Time to Low Output Level	$I_F=1.6\text{mA}$; $R_L=2.2\text{k}\Omega$	t_{PHL}	6N138	-	1.6	10	μs
	$I_F=0.5\text{mA}$; $R_L=4.7\text{k}\Omega$		6N139	-	5	25	
	$I_F=12\text{mA}$; $R_L=270\Omega$			-	0.1	1	
Propagation Delay Time to High Output Level	$I_F=1.6\text{mA}$; $R_L=2.2\text{k}\Omega$	t_{PLH}	6N138	-	10	35	μs
	$I_F=0.5\text{mA}$; $R_L=4.7\text{k}\Omega$		6N139	-	18	60	
	$I_F=12\text{mA}$; $R_L=270\Omega$			-	2	7	
Logic High Common Mode Transient Immunity	$I_F=0\text{mA}$; $ V_{\text{CM}} =10\text{V}_{\text{p-p}}$ $R_L=2.2\text{k}\Omega$	$ CM_H $	6N138	1	10	-	KV/ μs
			6N139				KV/ μs
Logic Low Common Mode Transient Immunity	$I_F=1.6\text{mA}$; $ V_{\text{CM}} =10\text{V}_{\text{p-p}}$ $R_L=2.2\text{k}\Omega$	$ CM_L $	6N138	1	10	-	KV/ μs
			6N139				KV/ μs

*All Typical at $T_A=25^{\circ}\text{C}$

Isolation Characteristics

Parameter	Test Condition	Symbol	Min	Typ	Max	Units
Input-Output Insulation Leakage Current	45% RH, t = 5s, V _{I-O} = 3kV DC, T _A = 25°C	I _{I-O}			1.0	μA
Withstand Insulation Test Voltage	RH ≤ 50%, t = 1min, T _A = 25°C	V _{ISO}	5000			V _{RMS}
Input-Output Resistance	V _{I-O} = 500V DC	R _{I-O}		10 ¹²		Ω

*All Typical at T_A = 25°C

Notes,

1. AC For 1 Minute, R.H. = 40 ~ 60%. Isolation voltage shall be measured using the following method.
(1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
(2) The isolation voltage tester with zero-cross circuit shall be used.
(3) The waveform of applied voltage shall be a sine wave.
2. For 10 Seconds
3. Current Transfer Ratio (CTR) is defined as the ration of output collector current, I_o, to the forward LED input current, I_F, times 100%.
4. Pin 7 open.
5. Instantaneous common mode rejection voltage "output (1)" represents a common mode voltage variation that can hold the output above (1) level (V_o > 2.0V). Instantaneous common mode rejection voltage "output (0)" represents a common mode voltage variation that can hold the output above (0) level (V_o < 0.8V).
6. Device considered a two terminal device. Pins 1, 2, 3 and 4 shorted together and Pins 5, 6, 7 and 8 shorted together.

Switching Time Test Circuit

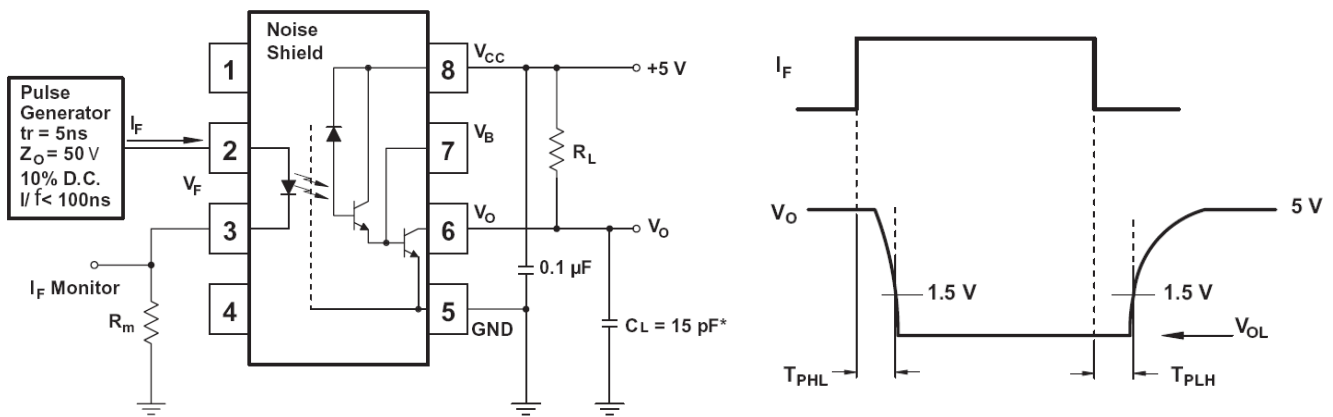


Figure 1: Single Channel Test Circuit for t_{PHL} and t_{PLH}

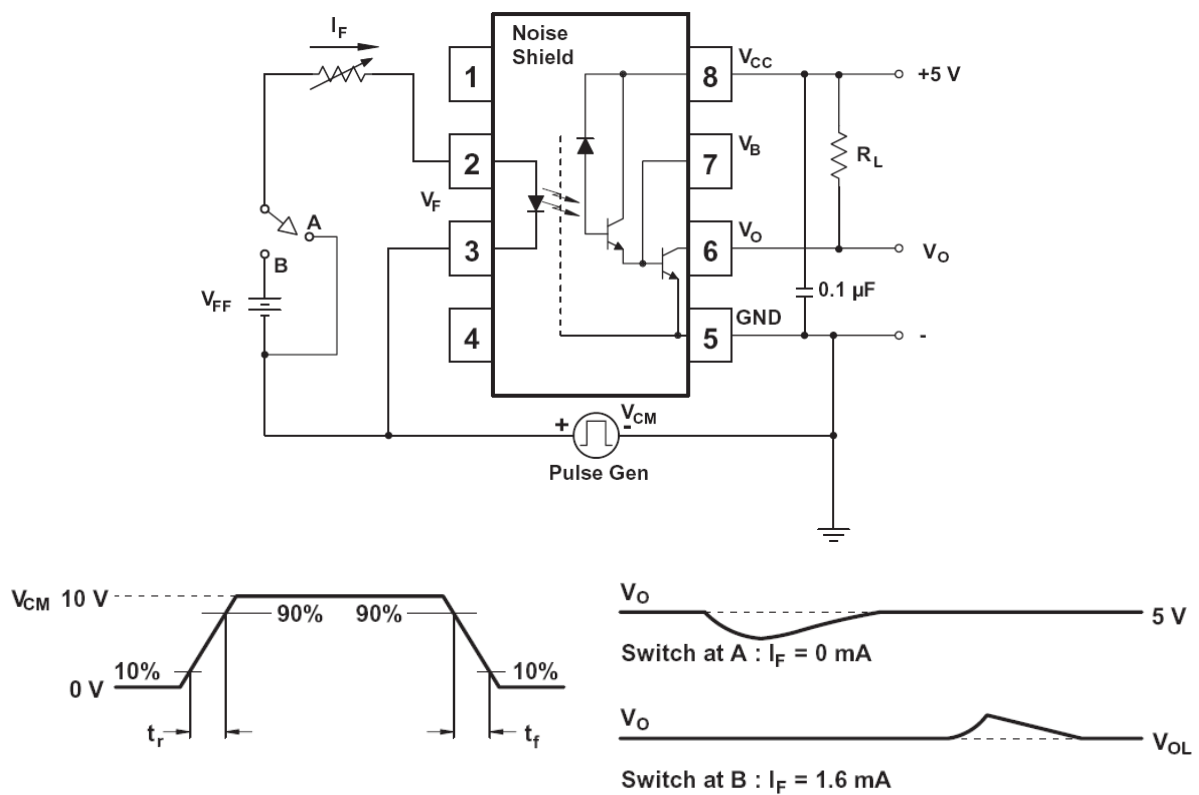


Figure 2: Single Channel Test Circuit for Common Mode Transient Immunity

Characteristics Curves

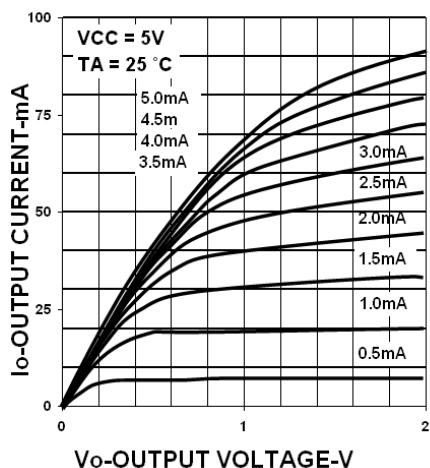


Figure 3: DC transfer characteristics

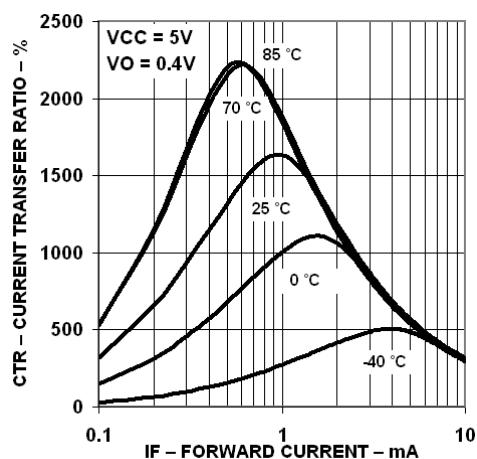


Figure 4: current transfer ratio vs. forward current

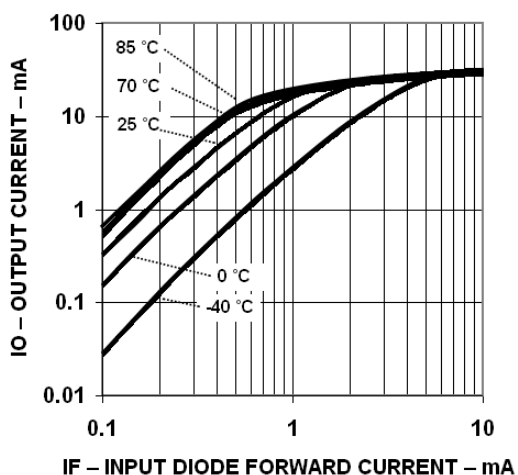


Figure 5: output current vs. input diode forward current

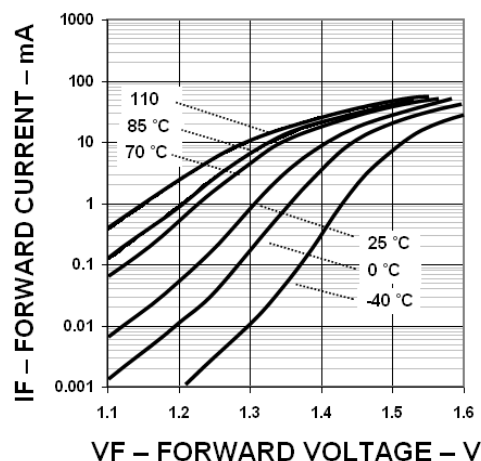


Figure 6: Input diode forward current vs. forward voltage

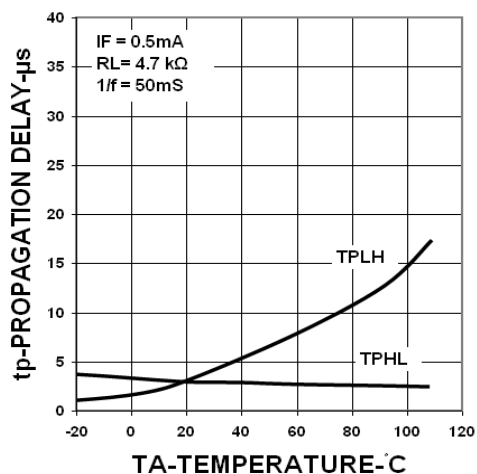


Figure 7: 6N139 propagation delay vs. temperature

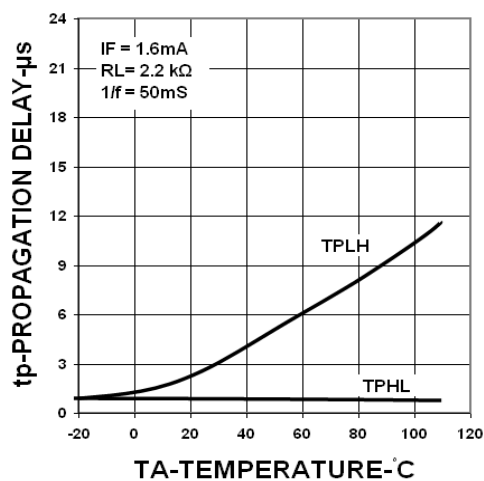


Figure 8: 6N138 propagation delay vs. temperature

Characteristics Curves

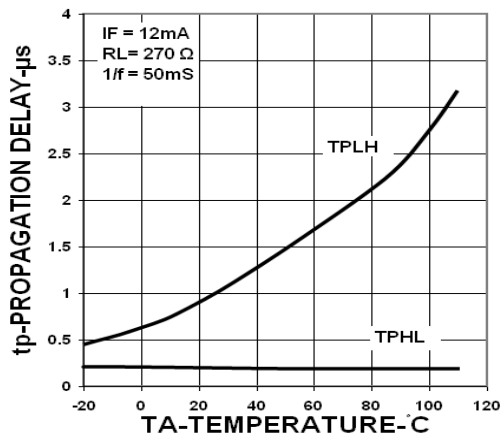


Figure 9: 6N139 propagation delay vs. temperature

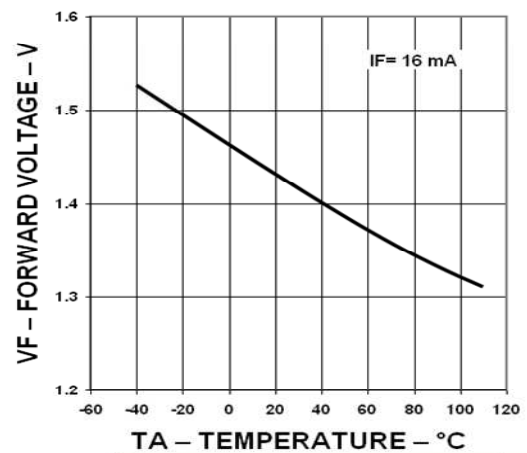


Figure 10: Forward voltage vs. temperature

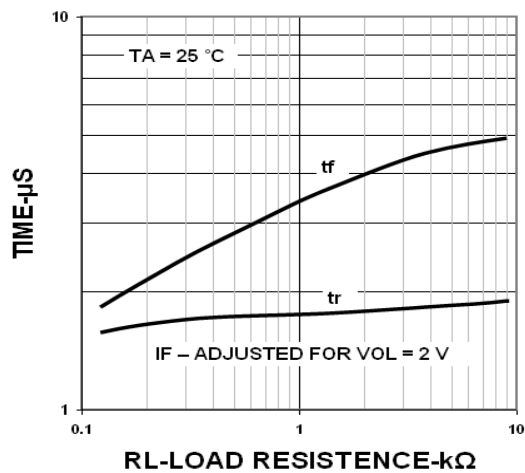


Figure 11: Non-saturated rise and fall time vs. load resistance

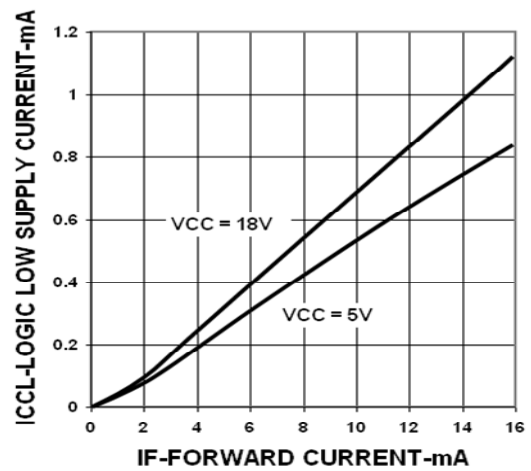


Figure 12: Logic low supply current vs. forward current

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Notes:

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